

ALM-GA002

GPS Low Noise Amplifier Variable Current/Shutdown Function



Data Sheet

Description

Avago Technologies's ALM-GA002 is a LNA designed for GPS/ISM/Wimax applications in the (0.9-2.4)GHz frequency range. The LNA uses Avago Technologies's proprietary GaAs Enhancement-mode pHEMT process to achieve high gain operation with very low noise figures and high linearity. Noise figure distribution is very tightly controlled. Gain and supply current are guaranteed parameters. A CMOS compatible shutdown pin is included to turn the LNA off and provide a variable bias.

The ALM-GA002 LNA is usable down to 1 V operation. It achieves low noise figures and high gain even at 1V, making it suitable for use in critical low power GPS/ISM band applications.

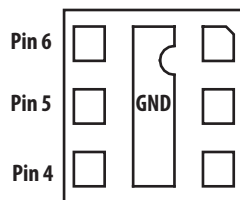
Package Marking and Orientation



Top View

Note: Package marking provides Orientation and identification:
"B" = Product Code
"Y" = Year
"WW" = Work Week

Pin Configuration



Bottom View

LNA I/O's :
1. NC
2. RF_IN
3. NC
4. VSD
5. RF_OUT
6. VDD

Features

- Operating temperature range -40 to +85 °C
- Surface Mount 2.0 x 2.0 x 1.1 mm³ MCOB
- Advanced GaAs E-pHEMT
- Low Noise: 0.8 dB typ
- High Gain: 14.3 dB typ
- Low component count
- High IIP3 and IP1dB
- Wide Supply Voltage: 1 V to 3.6 V
- Shutdown current: < 0.1 μ A
- CMOS compatible shutdown pin (VSD) current @ 2.85 V: 90 μ A
- Adjustable bias current via one single external resistor/voltage
- Small Footprint: 2x2 mm²
- Low Profile: 1.1 mm typ.
- Lead-free and Halogen-free
- Ext matching for non-GPS freq band operation

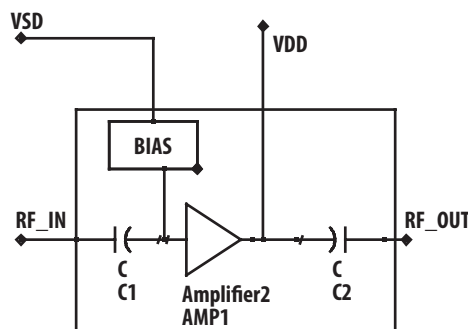
Specifications (25 deg):

At 1.575GHz, 2.85 V 8 mA (Typ)

- Gain = 14.3 dB (Typ)
- NF = 0.8 dB (Typ)
- IIP3 = 4.7 dBm (Typ)
- IP1dB = 1.8 dBm (Typ)
- S11 = -11.8 dB (Typ)
- S22 = -12.4 dB (Typ)

Note: Measurements obtained using demoboard described in Figure 4.

Simplified Schematic



Absolute Maximum Ratings^[1]

Symbol	Parameter	Units	Absolute Maximum
V _{DS}	Drain – Source Voltage ^[2]	V	3.6
I _{DS}	2G Drain Current ^[2]	mA	15
P _{diss}	Total Power Dissipation ^[3]	mW	54
P _{in max.}	RF Input Power	dBm	+10
T _{CH}	Channel Temperature	°C	150
T _{STG}	Storage Temperature	°C	-65 to 150
θ _{ch_b}	Thermal Resistance ^[4]	°C/W	232

Notes:

1. Operation of this device above any one of these parameters may cause permanent damage.
2. Assuming DC quiescent conditions.
3. Board (package belly) temperature T_B is 25°C. Derate 4.32mW/°C for T_B > 137°C.
4. Channel-to-board thermal resistance measured using 150°C Liquid Crystal Measurement method.

Electrical Specifications

T_A = 25°C, DC bias for RF parameter is VDD = VSD = +2.85V @ 8mA (unless otherwise specified)

Table 1. Performance table at nominal operating conditions

VDD= VSD = +2.85V, R1 = 18K Ohm, Freq=1.575GHz – Typical Performance

Symbol	Parameter and Test Condition	Units	Min.	Typ	Max.
G	Gain	dB		14.3	
NF	Noise Figure	dB		0.8	
IP1dB	Input 1dB Compressed Power	dBm		1.8	
IIP3	Input 3 rd Order Intercept Point (2-tone @ Fc +/- 2.5MHz)	dBm		4.7	
S11	Input Return Loss	dB		-11.8	
S22	Output Return Loss	dB		- 12.4	
I _{ds}	Supply Current	mA		8	
I _{sh}	Shutdown Current @ VSD = 0V	uA		0.1	
V _{ds}	Supply Voltage	V		2.85	
IP1dB _{1710M}	Out of Band IP1dB (DCS 1710MHz) blocking	dBm		2.9	
IIP3 _{OUT}	Out of Band IIP3 (DCS 1775MHz & 1950MHz)	dBm		5.5	

Table 2. Typical performance at low operation voltages with R1 (see Fig 2) set to 0 Ohm

VDD = +2V, VDD= +1.5V & VDD= +1.0V, Freq=1.575GHz – Typical Performance
(VSD=VDD, R1=0 Ohm)

Symbol	Parameter and Test Condition	Units	VDD = 2V	VDD = 1.5V	VDD = 1.0V
G	Gain	dB	15	14.2	12.3
NF	Noise Figure	dB	0.8	0.9	1
IP1dB	Input 1dB Compressed Power	dBm	-1.4	-2.4	-3.8
IIP3	Input 3 rd Order Intercept Point (2-tone @ Fc +/- 2.5MHz)	dBm	7.3	4.9	5.2
S11	Input Return Loss	dB	-13.8	-11.5	-8
S22	Output Return Loss	dB	-15.5	-14.5	-11.7
I _{ds}	Supply Current	mA	13	7.5	3.6
I _{sh}	Shutdown Current @ VSD = 0V	uA	0.1	0.1	0.1
V _{ds}	Supply Voltage	V	2	1.5	1.0
IP1dB _{1710M}	Out of Band IP1dB (DCS 1710MHz) blocking	dBm	-0.3	-1.9	-2.9
IIP3 _{OUT}	Out of Band IIP3 (DCS 1775MHz & 1950MHz)	dBm	8.7	5.8	3

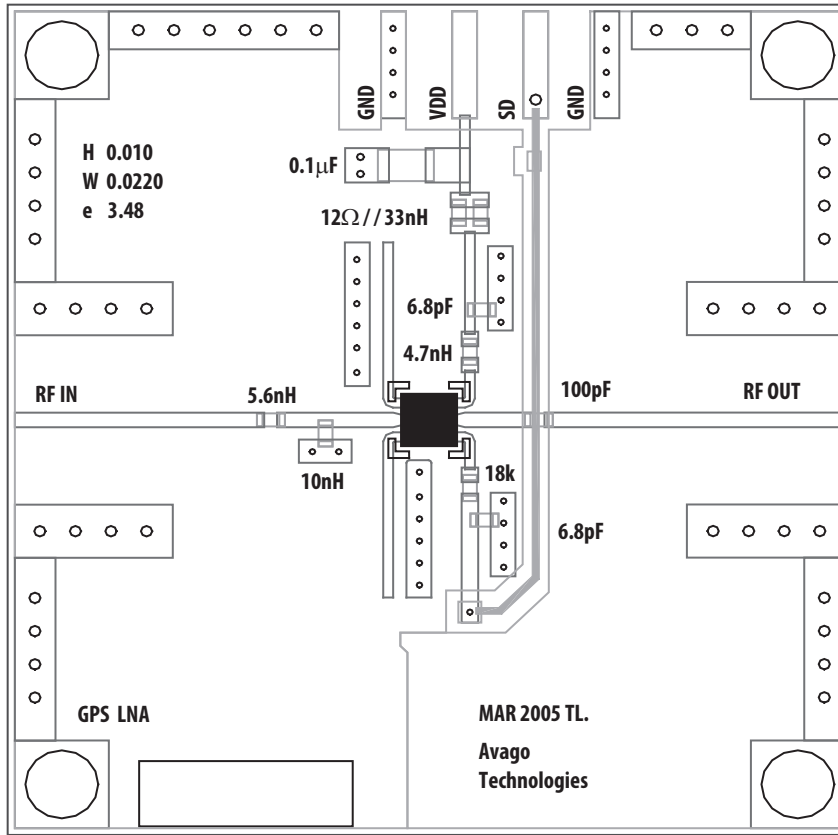


Figure 1. Demoboard and Application Circuit Components

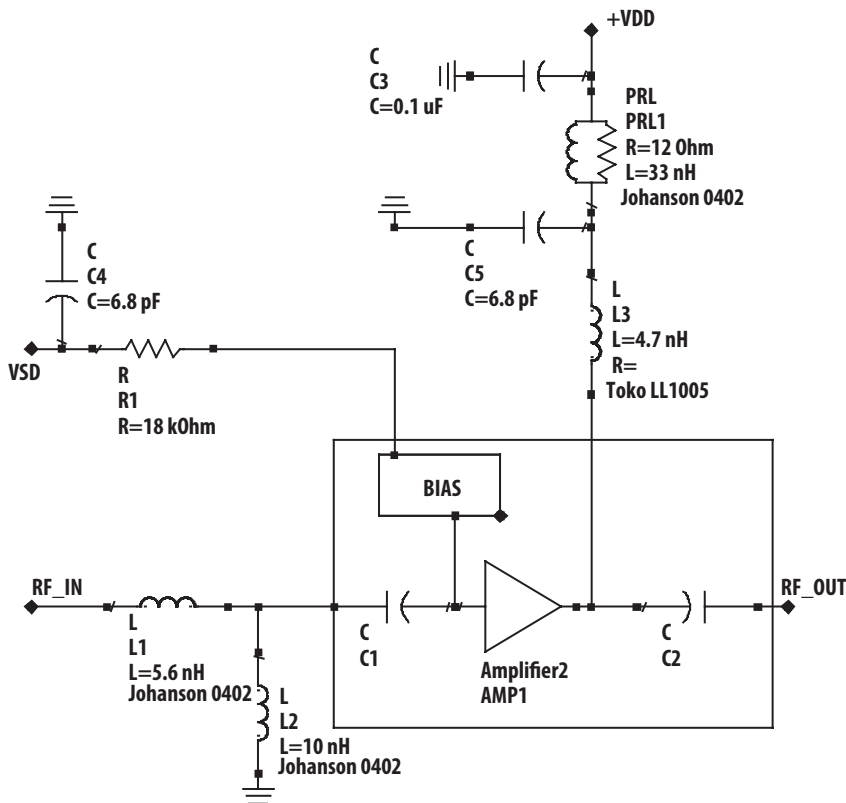


Figure 2. Demoboard schematic

Notes

- L1 and L2 form the input matching network. The LNA module has a integrated coupling and DC-blocking capacitors at the input and output. Best noise performance is obtained using high-Q wirewound inductors. This circuit demonstrates that low noise figures are obtainable with standard 0402 chip inductors. Replacing L1, L2 and L3 with high-Q wirewound inductors (eg. Cilcraft 0402CS series) will yield 0.1dB lower NF and 0.6dB higher Gain.
- L3 is an output matching inductor.
- C5 is a RF bypass capacitor.
- PRL1 is a network that isolates the measurement demoboard from external disturbances. C3 and C4 mitigates the effect of external noise pickup on the VSD and VDD lines. These components are not required in actual operation.
- Bias control is achieved by either varying the VSD voltage without R1 or fixing the VSD voltage to VDD and varying R1. Typical value for R1 is 18k Ohm for 8mA total current at VDD=+2.85V.
- Higher gain and IP3 performance can be obtained by increasing the supply current. This can be achieved by reducing the value for R1 to obtain desired current.
- For low voltage operation such as 1.5V or 1.0V, the R1 may be omitted and VSD connected directly to the supply pins.

ALM-GA002 Typical Performance Curves, $R1 = 18K\ \Omega$ (At 25°C unless specified otherwise)

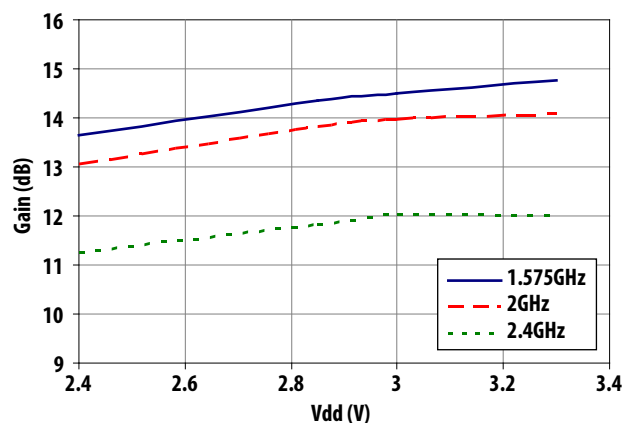


Figure 3. Gain vs Vdd vs Freq

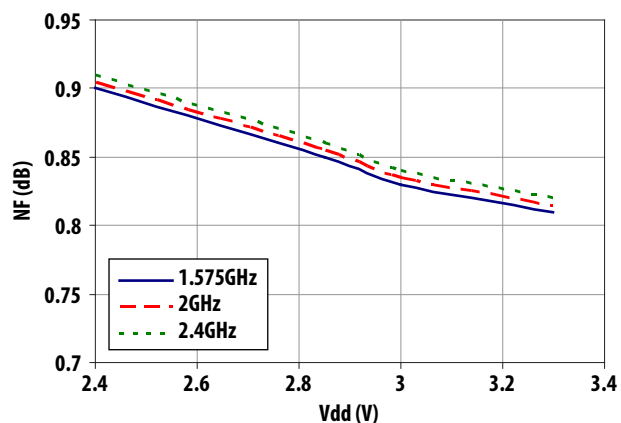


Figure 4. NF vs Vdd vs Freq

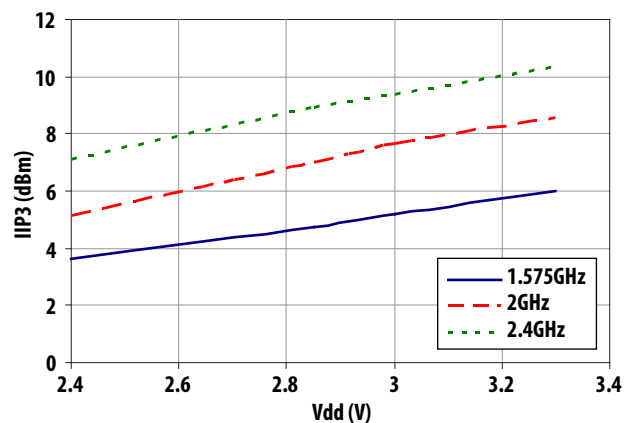


Figure 5. IIP3 vs Vdd vs Freq

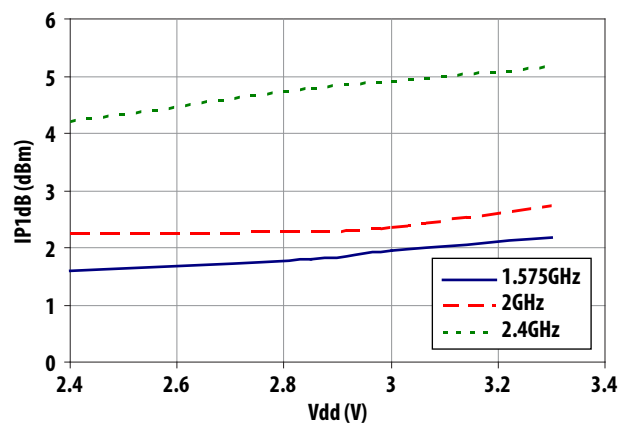


Figure 6. IP1dB vs Vdd vs Freq

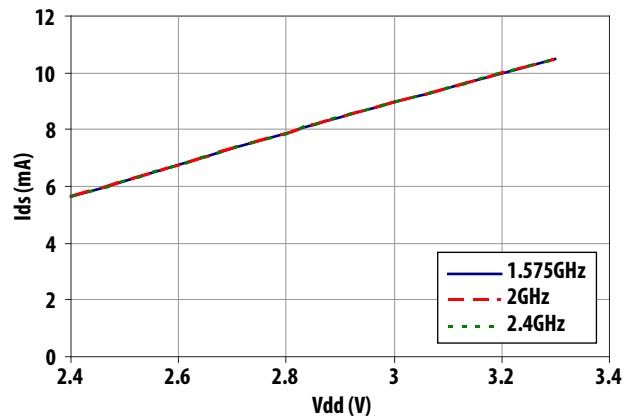


Figure 7. Ids vs Vdd vs Freq

ALM-GA002 Typical Performance Curves, R1 = 18K Ohm (At 25°C unless specified otherwise)

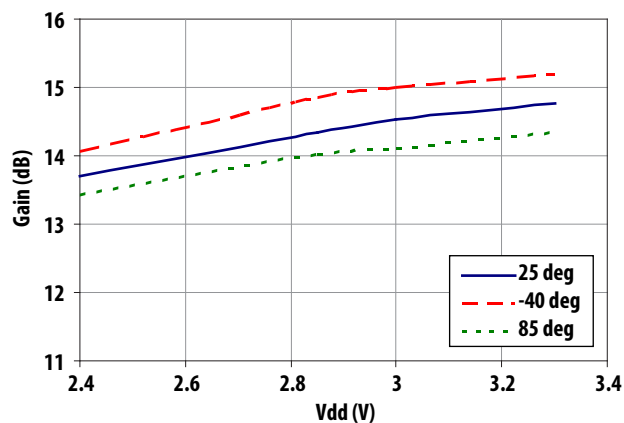


Figure 8. Gain vs Vdd vs Temp

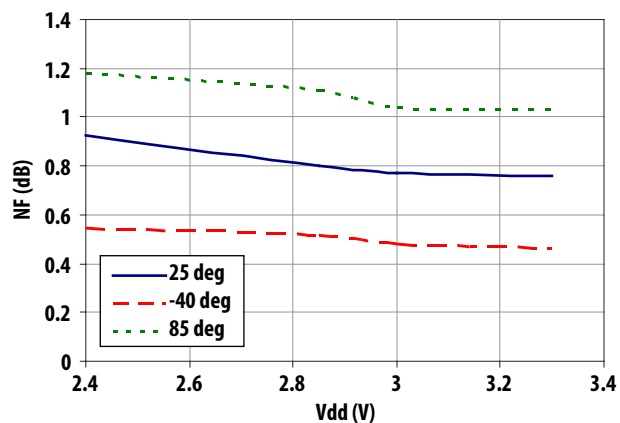


Figure 9. NF vs Vdd vs Temp

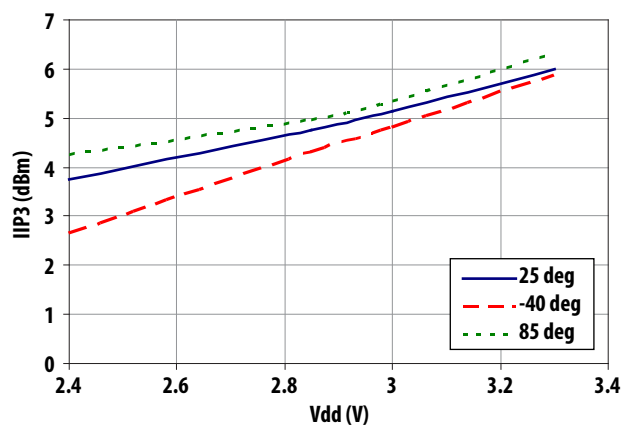


Figure 10. IIP3 vs Vdd vs Temp

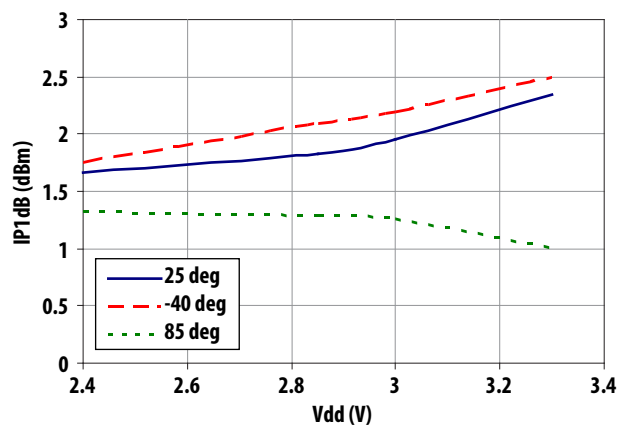


Figure 11. IP1dB vs Vdd vs Temp

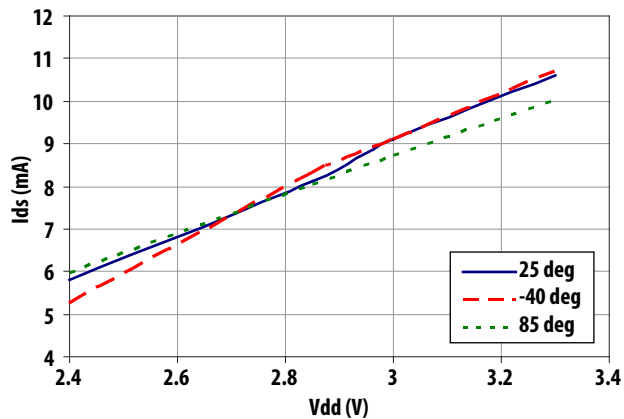


Figure 12. Ids vs Vdd vs Temp

ALM-GA002 Typical Scattering Parameters at 25°C, $V_{DD} = 2.85V$, $I_{DS} = 8\text{ mA}$

Freq. (GHz)	S11		S21			S12			S22	
	Mag.	Ang.	(dB)	Mag.	Ang.	(dB)	Mag.	Ang.	Mag.	Ang.
0.1	0.998	-4.7	15.01	5.633	176.7	-47.96	0.004	89.2	0.526	-5
0.5	0.946	-23.5	14.62	5.381	153.1	-34.42	0.019	78.6	0.503	-19
0.9	0.866	-40.4	13.72	4.854	134.1	-29.90	0.032	71.8	0.475	-31.9
1	0.843	-44.4	13.47	4.714	129.7	-29.37	0.034	70.5	0.468	-34.9
1.1	0.821	-48.2	13.20	4.573	125.5	-28.64	0.037	69.3	0.459	-37.9
1.2	0.8	-52	12.95	4.44	121.5	-27.96	0.04	68.5	0.451	-40.5
1.3	0.78	-55.8	12.69	4.31	117.6	-27.33	0.043	67.4	0.443	-43.2
1.4	0.757	-59.7	12.42	4.178	113.6	-26.94	0.045	66.5	0.435	-45.8
1.5	0.731	-63.4	12.13	4.039	109.7	-26.38	0.048	65.7	0.428	-48.2
1.6	0.705	-66.8	11.83	3.905	106.1	-26.02	0.05	64.8	0.421	-50.7
1.7	0.683	-69.7	11.55	3.78	102.9	-25.51	0.053	64.7	0.414	-52.8
1.8	0.663	-71.6	11.29	3.669	99.5	-25.19	0.055	63.9	0.408	-55.5
1.9	0.643	-73.4	10.99	3.544	96	-24.73	0.058	63.1	0.399	-58
2	0.623	-75.3	10.48	3.343	97	-24.58	0.059	66.3	0.398	-58.8
2.1	0.603	-77.2	10.25	3.253	93.5	-24.15	0.062	65.5	0.398	-59.6
2.2	0.583	-79	10.01	3.165	90.2	-23.74	0.065	64.6	0.397	-60.3
2.3	0.563	-80.9	9.77	3.079	87	-23.48	0.067	63.8	0.396	-61.1
2.4	0.543	-82.8	9.49	2.983	83.8	-23.10	0.07	63	0.396	-62.1
2.5	0.522	-85.3	9.23	2.895	81.1	-22.73	0.073	62.3	0.395	-62.7
3	0.434	-105.2	7.95	2.498	66.6	-21.21	0.087	56.9	0.345	-74.4
3.5	0.334	-119.5	6.47	2.105	57.3	-20.26	0.097	54	0.324	-86.8
4	0.302	-132.1	6.25	2.054	48.8	-18.42	0.12	53.7	0.271	-108
4.5	0.297	-141.8	5.50	1.883	33.1	-16.95	0.142	43.4	0.265	-113.3
5	0.274	-157.1	4.44	1.667	23.9	-15.97	0.159	38	0.259	-118.6
5.5	0.254	-170.1	3.63	1.519	16.1	-15.04	0.177	33.7	0.26	-133.2
6	0.211	178.7	2.82	1.383	6.3	-14.11	0.197	25.3	0.249	-142.7
6.5	0.204	165.4	1.89	1.243	-0.7	-13.64	0.208	16.7	0.263	-154.7
7	0.189	137.1	1.56	1.197	-5.4	-13.27	0.217	12.7	0.306	-171.3
7.5	0.193	117.3	1.03	1.126	-14.4	-12.88	0.227	9.5	0.31	179.8
8	0.206	90.6	0.87	1.105	-22.2	-12.40	0.24	4.7	0.314	170.8

ALM-GA002 Typical Noise Parameters, $V_{DD} = 2.85V$, $I_{DS} = 8mA$

Freq GHz	F_{min} dB	Γ_{opt} Mag.	Γ_{opt} Ang.	Rn/50	NF @ 50 dB
0.5	0.53	0.64	13.8	0.41	1.46
0.9	0.65	0.69	32.2	0.28	1.07
1.5	0.8	0.71	47.4	0.24	1.22
1.7	0.82	0.69	58.1	0.22	1.14
2	0.91	0.68	59.5	0.23	1.1
2.4	0.93	0.64	71.3	0.27	1.72
3	1.21	0.52	99.2	0.16	1.45
3.5	1.33	0.44	135.8	0.12	1.6
4	1.69	0.35	161.3	0.08	1.27
4.5	1.73	0.31	171.3	0.06	1.47
5	1.82	0.32	-179.6	0.06	1.65
5.5	1.98	0.34	-171.2	0.08	2.16
5.8	2.37	0.43	-174.8	0.14	2.88

Part Number Ordering Information

Part Number	No. of Devices	Container
ALM-GA002-BLKG	100	antistatic bag
ALM-GA002-TR1G	3000	7" Reel

Package Dimensions

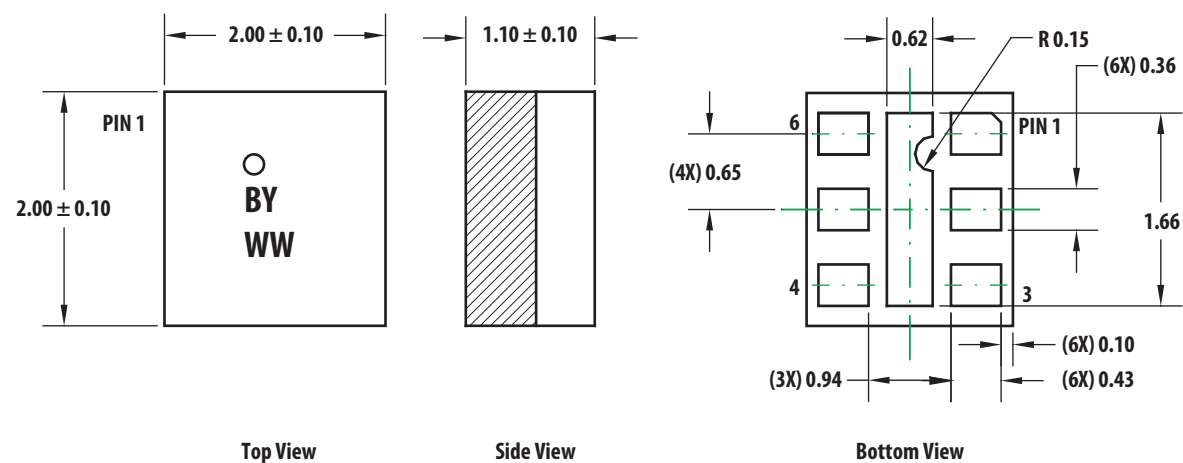


Figure 1 illustrates the carrier tape and reel assembly. The diagram shows a reel of carrier tape with labels: REEL, USER FEED DIRECTION, CARRIER TAPE, COVER TAPE, and TOP VIEW. The top view shows a carrier tape with three sprocket holes and three rectangular windows, each containing the text "BY WW". An end view shows the profile of the carrier tape.

Technical drawing of a mechanical part, showing a top view and a cross-section B-B.

Top View Dimensions:

- Overall width: 8.10
- Overall height: 7.90
- Distance from top edge to centerline of holes: 1.85
- Distance from centerline of holes to bottom edge: 1.65
- Distance between hole centers (pitch): 4.00 ± 0.10 (SEE NOTE #2)
- Distance from left edge to first hole center: 1.20 ± 0.10
- Distance from first hole center to second hole center: 1.20 ± 0.10
- Distance from second hole center to third hole center: 4.00 ± 0.10
- Distance from third hole center to fourth hole center: 4.00 ± 0.10
- Distance from fourth hole center to right edge: 1.20 ± 0.10
- Distance from left edge to centerline of holes: 3.50 ± 0.10
- Distance from centerline of holes to right edge: 4.00 ± 0.10
- Hole diameters: $\varnothing 1.50$ THRU (top holes), $\varnothing 1.050$ THRU (bottom holes)
- Section lines A-A and B-B are indicated.

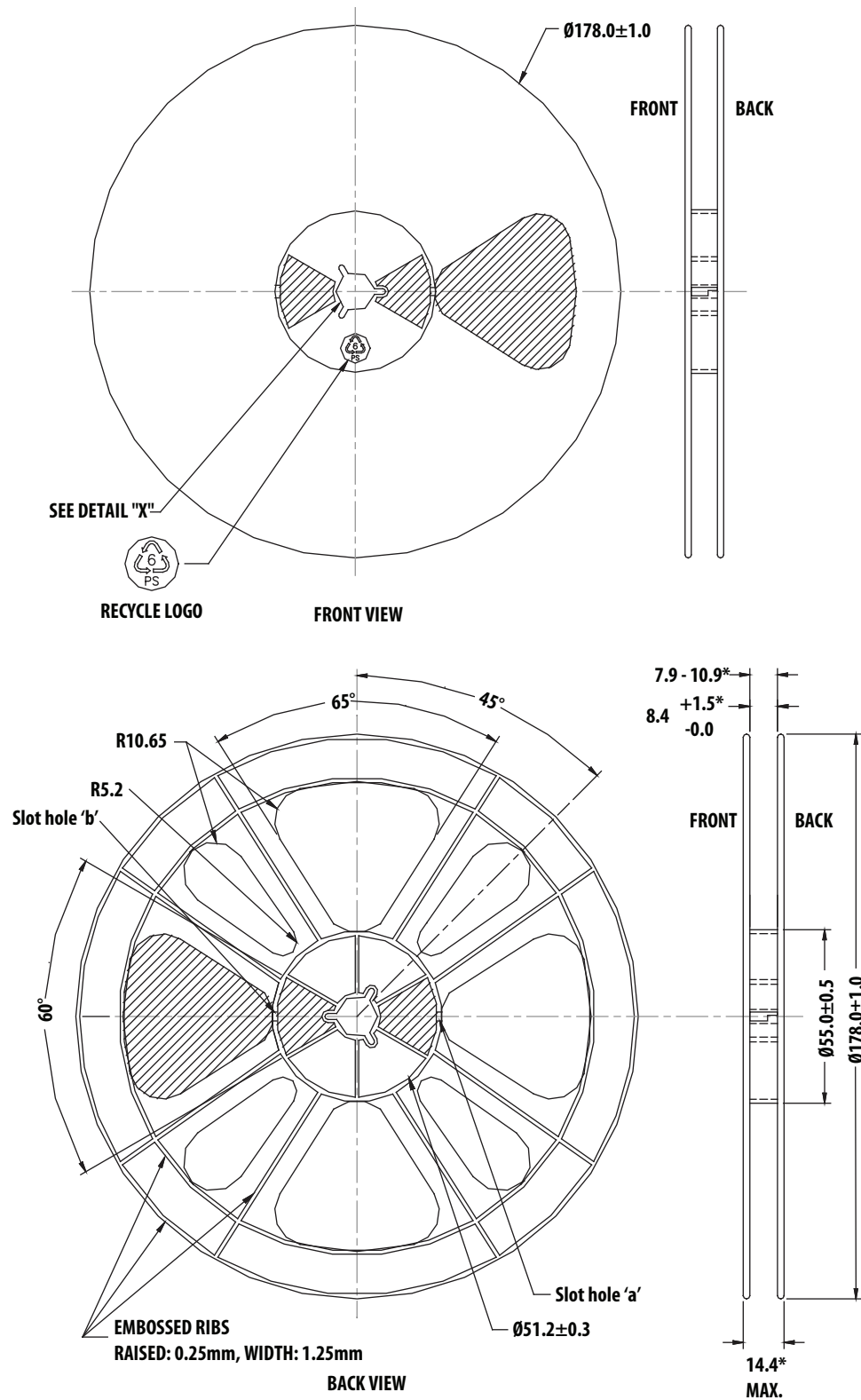
Section B-B Dimensions:

- Top flange thickness: 0.220
- Top flange width: 0.180
- Overall height: B0
- Bottom flange width: K0

1. Measured from centerline of sprocket hole to centerline of pocket
2. Cumulative tolerance of 10 sprocket holes is ± 0.20

All dimensions in millimeters unless otherwise stated.

Reel Dimensions



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AVAGO
TECHNOLOGIES